



## Retraction Note

# Retraction Note to: Singular vs. non-singular memorised relaxation for basic relaxation current of the capacitor

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## Retraction Note to: *Pramana – J. Phys.*

<https://doi.org/10.1007/s12043-019-1764-9>

The Editor has retracted this article [1] because there is significant overlap with another publication by the same author without proper citation [2]. The author agrees with this retraction.

## References

- [1] S Das, Singular vs. non-singular memorised relaxation for basic relaxation current of the capacitor, *Pramana – J. Phys.* **93**: 5 (2019), <https://doi.org/10.1007/s12043-019-1764-9>
- [2] S Das, Memorized relaxation with singular and non-singular memory kernels for basic relaxation of dielectric vis-à-vis Curie–Von Schweidler and Kohlrausch relaxation laws (March 2019), <https://doi.org/10.3934/dcdss.2020032>

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The original article can be found online at <https://doi.org/10.1007/s12043-019-1764-9>.